



## AMENDMENT TRANSMITTAL LETTER

Docket No.  
T2171.0196

Application No.  
09/873,580

Filing Date  
June 4, 2001

Examiner  
F. Toledo

Art Unit  
2823

Applicant(s): Harumitsu Fujita et al.

Invention: MULTI-VOLTAGE LEVEL SEMICONDUCTOR DEVICE AND ITS MANUFACTURE

### TO THE COMMISSIONER FOR PATENTS

Transmitted herewith is an amendment in the above-identified application.

The fee has been calculated and is transmitted as shown below.

#### CLAIMS AS AMENDED

	Claims Remaining After Amendment	Highest Number Previously Paid	Number Extra Claims Present	Rate	
Total Claims	4	- 8 =		x	
Independent Claims	1	- 1 =	0	x	
Multiple Dependent Claims (check if applicable) <input type="checkbox"/>					
Other fee (please specify):					
<b>TOTAL ADDITIONAL FEE FOR THIS AMENDMENT:</b>					

Large Entity

Small Entity

No additional fee is required for this amendment.

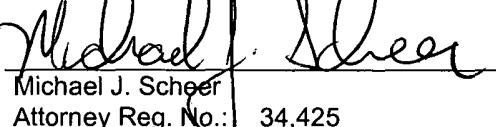
Please charge Deposit Account No. \_\_\_\_\_ in the amount of \$ \_\_\_\_\_.  
A duplicate copy of this sheet is enclosed.

A check in the amount of \$ \_\_\_\_\_ to cover the filing fee is enclosed.

The Commissioner is hereby authorized to charge and credit Deposit Account No. 04-1073  
as described below. A duplicate copy of this sheet is enclosed.

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Charge any additional filing or application processing fees required under 37 CFR 1.16 and 1.17.

  
Michael J. Scheer

Attorney Reg. No.: 34,425

Dated: March 12, 2002

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I hereby certify that this correspondence is being deposited with the U.S. Postal Service as Express Mail, Airbill No. EV 0595, U.S. in an envelope addressed to: Box Non-Fee Amendment, Commissioner for Patents, Washington, DC 20231, on the date shown below.

Dated: 3/12/02 Signature: Diane Albergo  
(Diane Albergo)

03-13-02

2823  
Docket No.: T2171.0196  
(PATENT)



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Initial Patent Application of:  
Tarumitsu Fujita

Application No.: 09/873,580

Group Art Unit: 2823

Filed: June 4, 2001

Examiner: F. Toledo

For: MULTI-VOLTAGE LEVEL  
SEMICONDUCTOR DEVICE AND ITS  
MANUFACTURE

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AMENDMENT

**Box Non-Fee Amendment**  
Commissioner for Patents  
Washington, DC 20231

Dear Sir:

In response to the Office Action mailed October 12, 2001, please amend the above-identified U.S. patent application as follows:

In the Specification:

Please amend the specification as follows:

On page 1, beneath the title:

This application is a divisional of 09/021,519 filed February 10, 1998, now U.S. Patent No. 6,271,572 which is based on Japanese patent application No. 9-28132, filed February 12, 1997, the whole contents of which are incorporated herein by reference.

In the Claims: